05/03/2017 504350111

PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1 Stylesheet Version v1.2 EPAS ID: PAT4396800

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
YI QI	05/03/2017
JIANWEI PENG	05/03/2017
YANPING SHEN	05/03/2017
HSIEN-CHING LO	05/03/2017
HUI ZHAN	05/03/2017

RECEIVING PARTY DATA

Name:	GLOBALFOUNDRIES INC.
Street Address:	PO BOX 309
Internal Address:	UGLAND HOUSE
City:	GRAND CAYMAN
State/Country:	CAYMAN ISLANDS
Postal Code:	KY1-1104

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	15585800

CORRESPONDENCE DATA

Fax Number: (713)434-6671

Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent

using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.

Phone: 7134346677

mpaul@amersoniplaw.com Email:

J. MIKE AMERSON **Correspondent Name:**

Address Line 1: 2500 FONDREN ROAD, SUITE 220

Address Line 4: HOUSTON, TEXAS 77063

ATTORNEY DOCKET NUMBER:	2162.276600/IMLT430
NAME OF SUBMITTER:	J. MIKE AMERSON
SIGNATURE:	/J. Mike Amerson/
DATE SIGNED:	05/03/2017
	This document serves as an Oath/Declaration (37 CFR 1.63).

PATENT REEL: 042228 FRAME: 0007

504350111

Total Attachments: 5 source=Declaration_and_Assignment#page1.tif source=Declaration_and_Assignment#page2.tif source=Declaration_and_Assignment#page3.tif source=Declaration_and_Assignment#page4.tif source=Declaration_and_Assignment#page5.tif

Title of Invention	METHODS OF FORMING EPI SEMICONDUCTOR MATERIAL ON THE SOURCE/DRAIN REGIONS OF A FINFET DEVICE
	DECLARATION
As the below	named inventor, I hereby declare that:
This declaration	
	United States application or PCT international application number filed on
The above-ide	entified application was made or authorized to be made by me.
I believe that	I am the original inventor or an original joint inventor of a claimed invention in the application.
I hereby acknowledge that any willful false statement made in this declaration is punishable under 18 U.S.C. 1001 by fine or imprisonment of not more than five (5) years, or both.	
	ed and understand the contents of the application and am aware of the duty to disclose to the US Patent and ffice all information known to me to be material to patentability as defined in 37 CFR § 1.56.
	ASSIGNMENT
For good and valuable consideration, the receipt, sufficiency and adequacy of which are hereby acknowledged, I hereby sell, assign, transfer, to GLOBALFOUNDRIES Inc. having a business address of PO Box 309, Ugland House, Grand Cayman KY1-1104 its successors and assigns, absolutely and forever, my entire right, title and interest in and to the invention listed above, together with the Application, any and all Patents that may issue in the United States and/or any foreign countries, and any reissues, re-examinations, renewals, continuations, continuation-in-parts, divisionals or extensions thereof that may be issued or granted, and all right, title and interest to the inventions contained in said Patents and Applications, for the United States and all foreign countries, and all the rights and privileges relating thereto including but not limited to the priority rights arising from said Applications, the right to recover and take all such proceedings as may be necessary for the recovery of damages or otherwise in respect of past, present and future infringement, and the right to apply for, take and maintain patents on said inventions.	
If any portion of this Combined Declaration or Assignment is held unenforceable, then remaining portions hereof shall nevertheless remain in full force and effect.	
LEGAL NAME OF INVENTOR	
Inventor:	YI QI Date: 20/7/5/3
Signature:	
	ication data sheet (PTO/SB/14 or equivalent), including naming the entire inventive entity, must accompany this form.

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Inventor:	Date: 05/03/2017	
Signature		
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LEGAL NAME OF INVENTOR			
Inventor:	YANPING SHEN Date: 05/03/201		
Signature:	SHIPPING -		
Note: An application data sheet (PTO/SB/14 or equivalent), including naming the entire inventive entity, must accompany this form. Use an additional form for each additional inventor.			

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	·	
LEGAL NAN	LEGAL NAME OF INVENTOR	
Inventor: HSIEN-CHING LO Date: 65/63/20/7		
Signature: UMU A		
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LEGAL NAME OF INVENTOR	
Inventor:	HUI ZHAN Date: 5/3/2017
Signature	: Mri
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RECORDED: 05/03/2017